Monolithic Digital IC

LB11995



# Three-Phase Brushless Motor Driver for CD-ROM Spindle Drive

#### **Overview**

The LB11995 is a 3-phase brushless motor driver especially suited for CD-ROM spindle motor drives.

#### **Functions**

- Current linear drive
- Control V type amplifier
- Separate power supply for output upper side bias circuit allows low output saturation by boosting this power supply only (useful for 5V power supply types).
- Upper side current detection technique reduces loss voltage of current detection resistor. Voltage drop caused by this resistor reduces internal power dissipation of IC.
- Built-in short braking circuit
- Built-in reverse blocking circuit
- Hall FG output
- Built-in S/S function
- Built-in current limiter circuit (selectable, 2 steps)
- Built-in Hall power supply
- Built-in thermal shutdown circuit
- Supports 3.3V DSP

### **Package Dimensions**

unit: mm **3227-HSOP24** 





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## Specifications

### Maximum Ratings at Ta = $25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage	V <sub>CC</sub> 1 max		7.0	V
	V <sub>CC</sub> 2 max		14.4	V
	V <sub>CC</sub> 3 max		14.4	V
Applied output voltage	V <sub>O</sub> max		14.4	V
Applied intput voltage	V <sub>IN</sub> max		V <sub>CC</sub> 1	V
Output current	I <sub>O</sub> max		1.3	А
Allowable power dissipation	Pd max	IC only	0.8	W
		with substrate (114.3 x 76.1 x 1.6 mm <sup>3</sup> , glass exposy)	1.9	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		–55 to +150	°C

### Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage	V <sub>CC</sub> 1		4 to 6	V
	V <sub>CC</sub> 2	$\geq V_{CC}1$	4 to 13.6	V
	V <sub>CC</sub> 3		4 to 13.6	V

#### Sample Application at Ta = $25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
12V type	V <sub>CC</sub> 1	Regulated voltage	4 to 6	V
	$V_{CC}^2 = V_{CC}^3$	Unregulated voltage	4 to 13.6	V
5V type	$V_{CC}1 = V_{CC}3$	Regulated voltage	4 to 6	V
	V <sub>CC</sub> 2	Boost-up voltage or regulated voltage (Note)	4 to 13.6	V

Note: When boost-up voltage is used at  $V_{CC}^2$ , output can be set to low-saturation.

# Electrical Characteristics at Ta = 25°C, $V_{CC}1 = 5V$ , $V_{CC}2 = V_{CC}3 = 12V$

Parameter	Symbol Conditions		Ratings			Unit
			min	typ	max	onit
[Power supply current]		-				
Power supply current	I <sub>CC</sub> 1	$V_{C} = V_{CREF}$		8		mA
	I <sub>CC</sub> 2	$V_{C} = V_{CREF}$		0		mA
	I <sub>CC</sub> 3	$V_{C} = V_{CREF}$		150	250	μΑ
Output idle current	I <sub>CC</sub> 10Q	$V_{S/S} = 0V$			200	μΑ
	I <sub>CC</sub> 2OQ	$V_{S/S} = 0V$			30	μΑ
	I <sub>CC</sub> 3OQ	$V_{S/S} = 0V$			30	μΑ
[Output]		• * * *				
Saturation voltage, upper side 1	V <sub>OU</sub> 1	$I_0 = -0.5A, V_{CC}1 = 5V, V_{CC}2 = V_{CC}3 = 12V$		1.0		V
lower side 1	V <sub>OD</sub> 1	$I_0 = 0.5A, V_{CC}1 = 5V, V_{CC}2 = V_{CC}3 = 12V$		0.3		V
Saturation voltage, upper side 2	V <sub>OU</sub> 2	$I_0 = -0.5A, V_{CC}1 = V_{CC}3 = 5V, V_{CC}2 = 12V$		0.3		V
lower side 2	V <sub>OD</sub> 2	$I_0 = 0.5A, V_{CC}1 = V_{CC}3 = 5V, V_{CC}2 = 12V$		0.3		V
Current limiter setting voltage	V <sub>CL</sub> 1	R <sub>RF</sub> = 0.33Ω, LMC; OPEN		0.24		V
	V <sub>CL</sub> 2	R <sub>RF</sub> = 0.33Ω, LMC; GND		0.35		V
[Hall amplifier]						
Common mode input voltage range	V <sub>HCOM</sub>		1.2		V <sub>CC</sub> 1–1.0	V
Input bias current	I <sub>HIB</sub>			1		μA
Minimum Hall input level	V <sub>HIN</sub>		60			mV <sub>P-P</sub>
[S/S pin]		•				
High level voltage	V <sub>S/SH</sub>		2.0		V <sub>CC</sub> 1	V
Low level voltage	V <sub>S/SL</sub>				0.7	V
Input current	I <sub>S/SI</sub>	$V_{S/S} = 5V$			200	μA
Leak current	I <sub>S/SL</sub>	$V_{S/S} = 0V$	-30			μA
[Control]	•					
V <sub>C</sub> pin input current	I <sub>VC</sub>	$V_{C} = V_{CREF} = 1.65V$			1	μA
V <sub>CREF</sub> pin input current	IVCREF	V <sub>C</sub> = V <sub>CREF</sub> = 1.65V			1	μΑ
Voltage gain		$\Delta V_{RF} \Delta V_{C}$		0.35		times
Startup voltage	V <sub>CTH</sub>	V <sub>CREF</sub> = 1.65V	1.5		1.8	V
Startup voltage width		V <sub>CREF</sub> = 1.65V	50		150	mV
[Hall power supply]	,	•				
Hall power supply voltage	V <sub>H</sub>	I <sub>H</sub> = 5 mA		0.8		V
Allowable current	Iн		20			mA
[Thermal shutdown]						
Operating temperature	T <sub>TSD</sub>	Design target value	150	180	210	°C
Hysteresis	ΔT <sub>TSD</sub>	Design target value		15		°C
[Short braking]	•	•				
Brake pin at High level	V <sub>BRH</sub>		4		5	V
Brake pin at Low level	V <sub>BRL</sub>		0		1	V

Note:

• During S/S OFF (standby), the Hall comparator is at High.

• Items shown to be design target values are not measured.

#### **Truth Table**

$\smallsetminus$	Courses		Hall input	Control	
	Source -> Sink	U	V	W	V <sub>C</sub>
1	Phase W -> Phase V	н	н		Н
	Phase V -> Phase W			-	L
2	Phase W -> Phase U	н	L	L	Н
-	Phase U -> Phase W				L
3	Phase V -> Phase W		L	н	Н
5	Phase W -> Phase V				L
4	Phase U -> Phase V		н	L	Н
4	Phase V -> Phase U				L
5	Phase V -> Phase U	н		н	Н
5	Phase U -> Phase V		Ľ	11	L
6	Phase U -> Phase W		н	н	Н
0	Phase W -> Phase U				L

Input:

H: Input 1 is higher in potential than input 2 by at least 0.2V.

L: Input 1 is lower in potential than input 2 by at least 0.2V.

### **Brake Operation Truth Table**

BRAKE pin	Operation	
н	Short brake	
Low or open	Normal rotation	

### **Pin Assignment**



A12337

## **Block Diagram**





### Sample Application Circuit 1 (12V Version)

Power supply - GND Output - GND Between Hall inputs Capacitor requirements may change depending on motor. For some motors, capacitor between Hall inputs may not be needed.



## Sample Application Circuit 2 (5V Version)

Power supply - GND Output - GND Between Hall inputs Capacitor requirements may change depending on motor. For some motors, capacitor between Hall inputs may not be needed.

## **Pin Descriptions**

Pin number	Pin name	Pin voltage	Equivalent circuit	Pin function
3	V <sub>CC</sub> 2	4V to 13.6V		Source side predrive voltage supply pin
4	V <sub>CC</sub> 3	4V to 13.6V		Constant current control amplifier voltage supply pin
6	V <sub>CC</sub> 1	4V to 6V		Power supply pin for all circuits except output transistors, source predriver, and constant current control amplifier
14	RS		100μA VCC1 100μA 14) 15	Reverse detector pin Forward rotation: High Reverse rotation: Low
15	FG		A12341	1 Hall element waveform Schmitt comparator composite output
8 7	U <sub>IN</sub> 1 U <sub>IN</sub> 2			U phase Hall element input and reverse detector U phase Schmitt comparator input pin Logic High indicates U <sub>IN</sub> 1 > U <sub>IN</sub> 2.
10 9	V <sub>IN</sub> 1 V <sub>IN</sub> 2	1.2V to V <sub>CC</sub> 1–1V		V phase Hall element input and reverse detector V phase Schmitt comparator input pin Logic High indicates V <sub>IN</sub> 1 > V <sub>IN</sub> 2.
12 11	W <sub>IN</sub> 1 W <sub>IN</sub> 2		25µA	W phase Hall element input and reverse detector W phase Schmitt comparator input pin Logic High indicates W <sub>IN</sub> 1 > W <sub>IN</sub> 2.
13	V <sub>H</sub>		V <sub>CC</sub> 1 75μA ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓	Hall element lower side bias voltage supply pin
17	S/S	0V to V <sub>CC</sub> 1	V <sub>CC</sub> 1 17 50kΩ \$ 17 17 17 17 17 17 17 17 17 17	When this pin is at 0.7V or lower, or when it is open, all circuits are inactive. When driving motor, set this pin to 2V or higher.
18	SIG GND			GND pin for all circuits except output
20	FC		$V_{CC1}$	Control loop frequency compensa- tor pin. Connecting a capacitor between this pin and GND prevents closed loop oscillation in current limiting circuitry.

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Pin number	Pin name	Pin voltage	Equivalent circuit	Pin function
21	V <sub>CREF</sub>	0V to V <sub>CC</sub> 1 -1.5V	15μΑ 🕡 25μΑ 🥡 25μΑ 🕡 15μΑ	Control reference voltage supply pin. Determines control start voltage.
22	v <sub>c</sub>	0V to V <sub>CC</sub> 1		Speed control voltage supply pin V type control technique $V_C > V_{CREF}$ : Forward $V_C < V_{CREF}$ : Slowdown (Reverse-blocking circuit prevents reverse rotation.)
23	W <sub>OUT</sub>		A LEUTU	W phase output
23	PWR GND			Output transistor GND
1	V <sub>OUT</sub>			V phase output
2	U <sub>OUT</sub>			U phase output
5	RF			Upper side output NPN transistor collector pin (common for all 3 phases). For current detection, connect resistor between $V_{CC}3$ pin and RF pin. Constant current control and current limiter works by detecting this voltage.
19	LMC		V <sub>CC</sub> 1	When this pin is connected to GND, the limiter setting current is increased by a factor of 1.5.
16	BRAKE		100μA ↓ Vcc1 100μA ↓ (16) 50kΩ ↓ (16) 112349	Short brake pin BRAKE: High> Short brake operation Low/Open> Motor drive operation

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